



ELECTRONIC COPY

LG784645702
Report verification at igi.org



April 24, 2026

IGI Report Number **LG784645702**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **OVAL BRILLIANT**

Measurements **11.44 X 8.19 X 5.01 MM**

GRADING RESULTS

Carat Weight **3.07 CARATS**

Color Grade **D**

Clarity Grade **FLAWLESS**

April 24, 2026

IGI Report Number **LG784645702**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **OVAL BRILLIANT**

Measurements **11.44 X 8.19 X 5.01 MM**

GRADING RESULTS

Carat Weight **3.07 CARATS**

Color Grade **D**

Clarity Grade **FLAWLESS**

ADDITIONAL GRADING INFORMATION

Polish **EXCELLENT**

Symmetry **EXCELLENT**

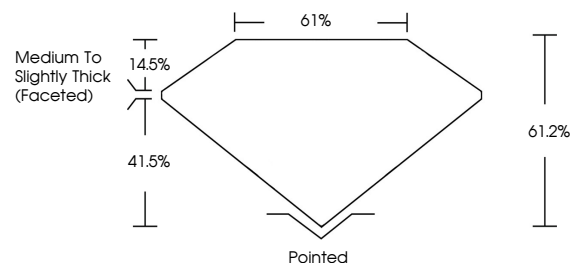
Fluorescence **NONE**

Inscription(s) **IGI LG784645702**

Comments: As Grown - No indication of post-growth treatment.

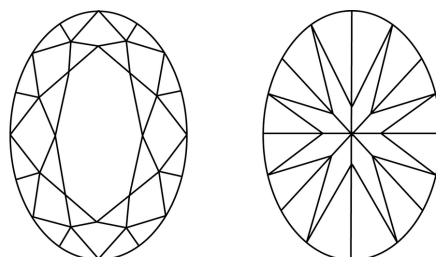
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

PROPORTIONS



Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

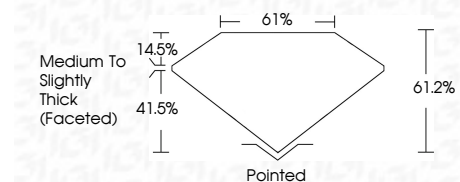
Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL	IF	VS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



ADDITIONAL GRADING INFORMATION

Polish **EXCELLENT**

Symmetry **EXCELLENT**

Fluorescence **NONE**

Inscription(s) **IGI LG784645702**

Comments: As Grown - No indication of post-growth treatment.

This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II



IGI



April 24, 2026
IGI Report No LG784645702
OVAL BRILLIANT
11.44 X 8.19 X 5.01 MM
Carat Weight 3.07 CARATS
Color Grade D
Clarity Grade FLAWLESS
Depth 61.2%
Table 61%
Girdle Medium to Slightly Thick (Faceted)
Culet Pointed
Polish EXCELLENT
Symmetry EXCELLENT
Fluorescence NONE
Inscription(s) IGI LG784645702

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II